



# Dual Operational Amplifier – LM158

Low power, Dual Operational Amplifier in bare die form

Rev 1.1  
21/01/18

## Description

The LM158 consists of x2 independent, high gain, internally frequency compensated operational amplifiers operating from a single power supply as low as 3V or as high as 32V. The device is useful in interface circuits with digital systems and can be operated from the single common 5V power supply. The device also finds use in transducer amplifiers, DC gain blocks & many other conventional op-amp circuits which benefit from the single power supply capability.  $I_Q$  per amplifier is about 1/5 of the industry 741. Split-supply operation is also possible with supply current drain independent of voltage supplied for low power. The die size is one of the smallest in the industry.

## Ordering Information

The following part suffixes apply:

- No suffix - MIL-STD-883 /2010B Visual Inspection
- "H" - MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- "K" - MIL-STD-883 /2010A Visual Inspection (space) + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

[www.siliconsupplies.com/quality/bare-die-lot-qualification](http://www.siliconsupplies.com/quality/bare-die-lot-qualification)

For a higher electrical grade version of this product see [LM158A](#)

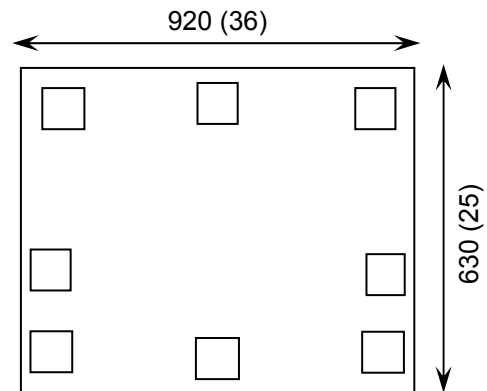
## Supply Formats:

- Default - Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <> 350µm(15 Mils) – On request
- Assembled into Ceramic Package – On request

## Features:

- Temperature compensated bandwidth (unity gain)
- Temperature compensated  $I_B$ : 45nA
- Wide power supply range, single supply: 3V-32V or dual supplies:  $\pm 1.5V$  to  $\pm 16V$
- Low  $V_{OS}$ : 2mV, and  $I_{OS}$ : 3nA
- Differential input voltage range equal to the power supply voltage
- Large output voltage: 0V to  $V_{CC} - 1.5V$  swing
- Input Common-Mode Voltage range includes GND

## Die Dimensions in µm (mils)



## Mechanical Specification

Die Size (Unsawn)	920 x 630 36 x 25	µm mils
Minimum Bond Pad Size	85 x 85 3.35 x 3.35	µm mils
Die Thickness	350 (±20) 13.78 (±0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µm	
Back Metal Composition	N/A – Bare Si	

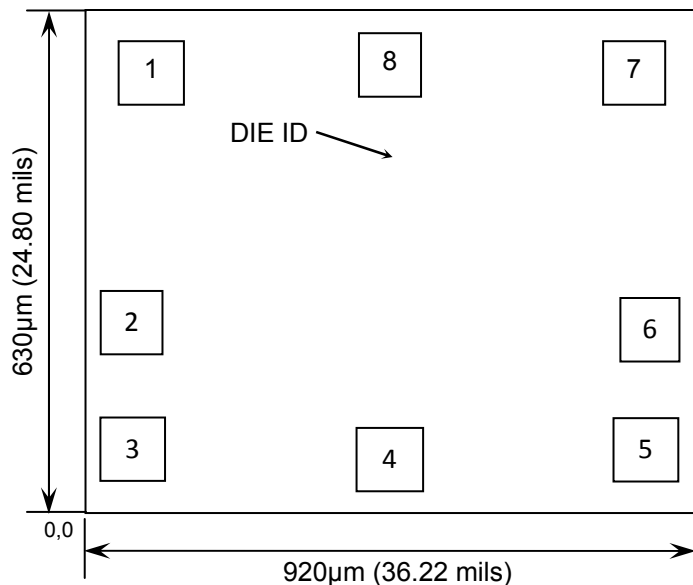




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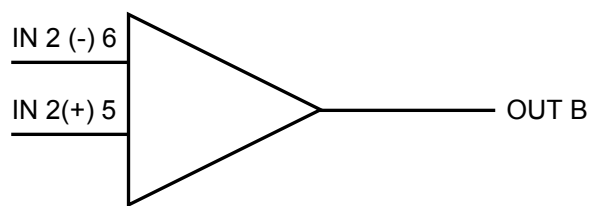
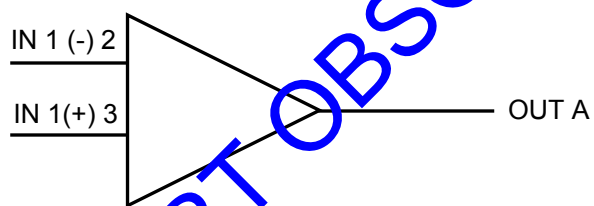
## Pad Layout and Functions



PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	OUTPUT A	0.1285	0.5015
2	- INPUT A	0.1125	0.2425
3	+ INPUT A	0.1125	0.1125
4	GND	0.4600	0.1075
5	+ INPUT B	0.8075	0.1125
6	- INPUT B	0.8075	0.2425
7	OUTPUT B	0.7915	0.5015
8	V <sub>CC</sub>	0.4600	0.5175

CHIP BACK POTENTIAL IS FLOAT

## Logic Diagram



PAD 8 = V<sub>CC</sub>

PAD 4 = GND

**\*\* PART OBSOLETE \*\***





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## Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage – Single Supply	$V_{CC}$	32	V
Supply Voltage – Split Supply		±16	V
Input Differential Voltage Range	$V_{IDR}$	32	V
Input Common Mode Voltage Range	$V_{ICR}$	-0.3 to 32	V
Output Short Circuit to Ground	-	Continuous	-
Junction Temperature	$T_J$	150	°C
Input Current (per pin) <sup>2</sup>	$I_{IN}$	50	mA

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.
2.  $V_{IN} < -0.3V$ . This input current exists when voltage is driven negative at any of the input leads.

## Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNITS
DC Supply Voltage	$V_{CC}$	±2.5 or 5	±15 or 30	V
Operating Temperature	$T_A$	-55	+125	°C

## DC Electrical Characteristics ( $T_A = -55^{\circ}C$ to $+125^{\circ}C$ unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS	
			MIN	TYP	MAX		
Input Offset Voltage	$V_{IO}$	$V_{IN} = 1.4V$ , $V_{CC} = 5V - 30V$ ; $R_S = 0\Omega$ , $V_{CM} = 0V$ to $V_{CC} - 1.7V$	25°C	-	2	5	mV
			125°C	-	-	7	
Input Offset Voltage Drift	$\Delta V_{IO} / \Delta T$	$V_{CC} = 30V$ ; $R_S = 0\Omega$	-	7	-	$\mu V / ^{\circ}C$	
Input Offset Current	$I_{IO}$	$V_{CC} = 5V$	25°C	-	3	30	nA
			125°C	-	-	100	
Input Offset Current Drift	$\Delta I_{IO} / \Delta T$	$V_{CC} = 30V$ ; $R_S = 0\Omega$	-	10	300	$pA / ^{\circ}C$	
Input Bias Current	$I_{IB}$	$V_{CC} = 5V$	25°C	-	45	150	nA
			125°C	-	40	300	
Supply Current	$I_{CC}$	$R_L = \infty, V_{CC} = 5V, V_O = 0V$	-	0.5	1.2	mA	
		$R_L = \infty, V_{CC} = 30V, V_O = 0V$	-	1	2		
Common Mode Input Voltage range	$V_{ICR}$	$V_{CC} = 30V$	25°C	0	-	$V_{CC} - 1.5$	V
			125°C	0	-	$V_{CC} - 2$	
Differential Input Voltage range	$V_{IDR}$	All $V_{IN} \geq GND$ or $V_{CC}^-$ (if used)	-	-	$V_{CC}$	V	





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## DC Electrical Characteristics continued ( $T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS	
			MIN	TYP	MAX		
Large-Signal Open-Loop Voltage Gain	$A_{VOL}$	$V_{CC} = 15\text{V}$ $R_L \geq 2\text{K}\Omega$	$25^\circ\text{C}$	50	100	-	V/mV
			$125^\circ\text{C}$	25	-	-	
Output High-Level Voltage swing	$V_{OH}$	$V_{CC} = 30\text{V}, R_L = 2\text{K}\Omega$	26	-	-	V	
		$V_{CC} = 30\text{V}, R_L = 10\text{K}\Omega$	27	28	-		
Output Low-Level Voltage swing	$V_{OL}$	$V_{CC} = 5\text{V}, R_L = 10\text{K}\Omega$	-	5	20	mV	
Common-Mode Rejection Ratio	CMRR	$V_{CC} = 30\text{V}, R_S = 10\text{K}\Omega,$ $T_A = 25^\circ\text{C}$	70	85	-	dB	
Power Supply Rejection Ratio	PSSR	$V_{CC} = 30\text{V},$ $T_A = 25^\circ\text{C}$	65	100	-	dB	
Crosstalk Attenuation	$V_{O1}/V_{O2}$	$f = 1\text{KHz to } 20\text{KHz}, V_{CC} = 30\text{V},$ $T_A = 25^\circ\text{C}$	-	-120	-	dB	
Output Short-Circuit current to GND	$I_{SC}$	$V_{CC} = 5\text{V}, V_O = 0\text{V}$ $T_A = 25^\circ\text{C}$	-	40	60	mA	
Output Source Current	$I_{SOURCE}$	$V_{IN+} = 1\text{V}, V_{IN-} = 0\text{V},$ $V_{CC} = 15\text{V}, V_O = 2\text{V}$	$25^\circ\text{C}$	20	40	-	mA
			$125^\circ\text{C}$	10	20	-	
Output Sink Current	$I_{SINK}$	$V_{IN+} = 0\text{V}, V_{IN-} = 1\text{V},$ $V_{CC} = 15\text{V}, V_O = 2\text{V}$	$25^\circ\text{C}$	10	20	-	mA
			$125^\circ\text{C}$	5	8	-	
		$V_{IN+} = 0\text{V}, V_{IN-} = 1\text{V},$ $V_{CC} = 15\text{V}, V_O = 0.2\text{V},$ $T_A = 25^\circ\text{C}$		12	50	-	$\mu\text{A}$

## Typical Characteristics

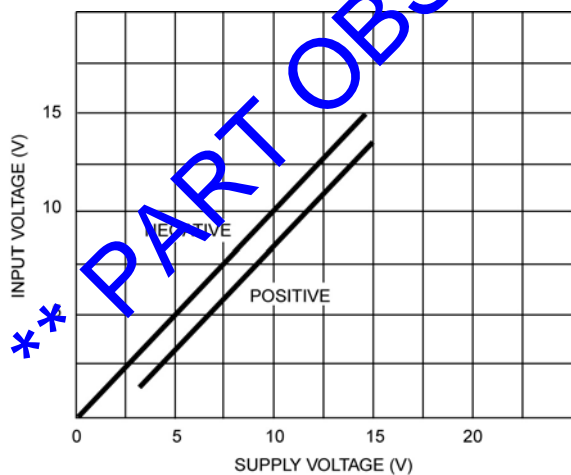


FIGURE 1. Input Voltage Range versus Supply Voltage

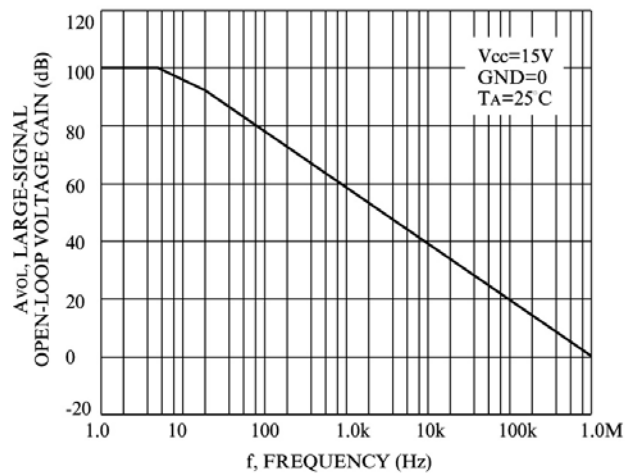


FIGURE 2. Open-Loop Frequency





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## Typical Characteristics continued

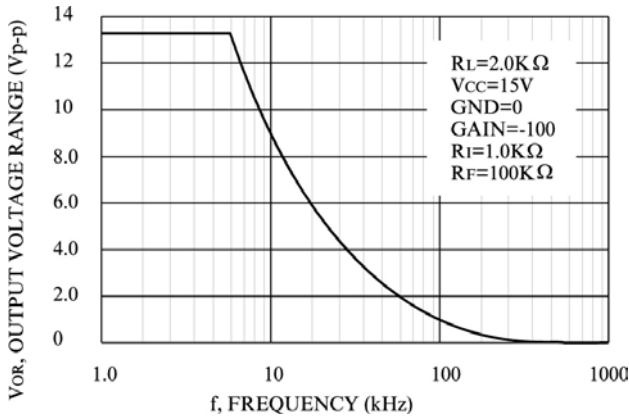


FIGURE 3. Large-Signal Frequency response

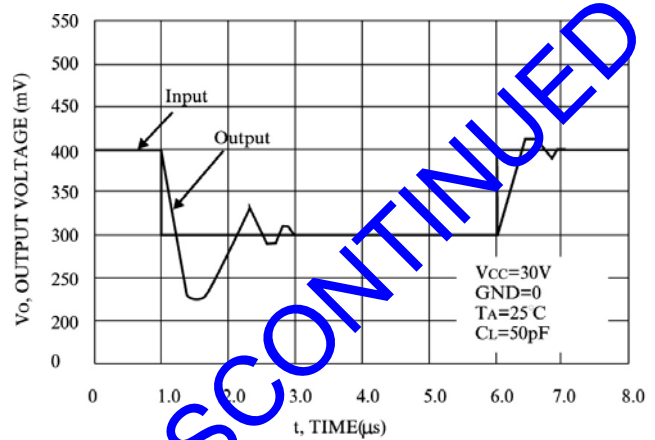


FIGURE 4. Small-Signal Voltage Follower Pulse Response (Non-inverting)

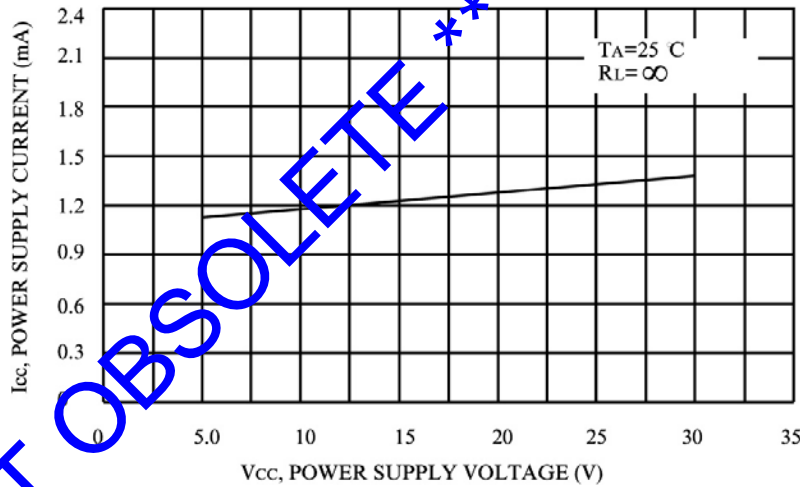


FIGURE 5. Power Supply Current versus Power Supply Voltage

**\*\* PART OBSOLETE \*\***





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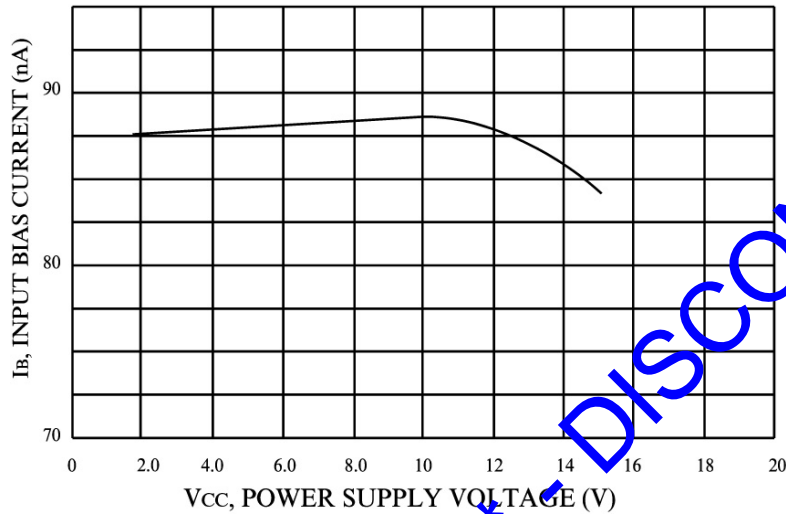


FIGURE 6. Low frequency Op-Amp with Offset adjust

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